



TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.

15624-US

In Re Application Of: Farsheed Mahmoudi et al.

| Serial No. | Filing Date | Examiner | Group Art Unit |
|------------|------------------|----------|----------------|
| 10/725,513 | December 3, 2003 | | 2681 |

Title: LOW-VOLTAGE LOW-POWER HIGH-LINEARITY ACTIVE CMOS MIXER

Address to:
Assistant Commissioner for Patents
Washington, D.C. 20231

37 CFR 1.97 (b)

- The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application; within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; or before the mailing date of a first Office Action on the merits, whichever event occurs last.

37 CFR 1.97 (c)

- The Information Disclosure Statement submitted herewith is being filed after three months of the filing of a national application, or the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; or after the mailing date of a first Office Action on the merits, whichever occurred last but before the mailing date of either:

1. a Final Action under 37 CFR 1.113, or
2. a Notice of Allowance under 37 CFR 1.311,

whichever occurs first.

Also submitted herewith is:

a certification as specified in 37 CFR 1.97(e);

OR

the fee set forth in 37 CFR 1.17(p) for submission of an Information Disclosure Statement under 37 CFR 1.97(c).



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(Under 37 CFR 1.97(b) or 1.97(c))

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(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

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37,547

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PTO/SB/08a (08-03)

Approved for use through 07/31/2006. OMB 0651-0031

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Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

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of

2

Complete if Known

| | |
|------------------------|-------------------|
| Application Number | 10/725,513 |
| Filing Date | December 3, 2003 |
| First Named Inventor | Farsheed Mahmoudi |
| Art Unit | 2681 |
| Examiner Name | |
| Attorney Docket Number | 15624-US |

U. S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

| FOREIGN PATENT DOCUMENTS | | | | | | |
|--------------------------|-----------------------|---|--------------------------------|--|---|----------------|
| Examiner Initials* | Cite No. ¹ | Foreign Patent Document | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | T ⁶ |
| | | Country Code ³ Number ⁴ Kind Code ⁵ (if known) | | | | |
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| Substitute for form 1449B/PTO | | | | <i>Complete if Known</i> | |
| | | | | <i>Application Number</i> | 10/725,513 |
| | | | | <i>Filing Date</i> | December 3, 2003 |
| | | | | <i>First Named Inventor</i> | Farsheed Mahmoudi |
| | | | | <i>Art Unit</i> | 2681 |
| | | | | <i>Examiner Name</i> | |
| Sheet | 2 | of | 2 | <i>Attorney Docket Number</i> | 15624-US |

| NON PATENT LITERATURE DOCUMENTS | | |
|---------------------------------|-----------------------|---|
| Examiner Initials* | Cite No. ¹ | |
| | | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. |
| | | KIM, Tae Wook et al., "Highly linear RF CMOS amplifier and mixer adopting MOSFET transconductance linearization by multiple gated transistors", IEEE, 2003, pages 107-110. |
| | | KIM, Youngwook et al., "Linearized mixer using predistortion technique", IEEE Microwave and Wireless Components Letters, Vol. 12, No. 6, 2002, pages 204-205. |
| | | Bautista, Edwin E. et al., "A high IIP2 downconversion mixer using dynamic matching", IEEE Journal of Solid-State Circuits, Vol. 35, No. 12, 2000, pages 1934-1941. |
| | | LI, Qiang et al. , "CMOS RF mixer no-linearity design", IEEE, 2001, pages 808-811. |
| | | WANG, Zhenhua et al., "A voltage-controllable linear MOS transconductor using bias offset technique", IEEE Journal of Solid-State Circuits, Vol. 25, No. 1, 1990, pages 315-317. |
| | | HEYDARI, Payam, "High-frequency noise in RF active CMOS mixers". |
| | | ROFOUGARAN, A. et al., "A1 GHz CMOS RF front-end IC with wide dynamic range". |
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| Examiner Signature | | Date Considered | |
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